


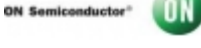
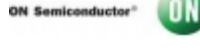
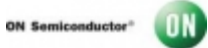


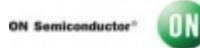
	<h2 style="color: red;">NVA4153NT1G</h2>
	<p>Hersteller-Teilenummer: NVA4153NT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 0.915A SC75</p> <p>Datenblätter:  NVA4153NT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVA4153NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 20V 0.915A SC75
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-75, SOT-416
Supplier Device-Gehäuse	SC-75, SOT-416
Verlustleistung (max)	300mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	915mA (Ta)
Rds On (Max) @ Id, Vgs	230 mOhm @ 600mA, 4.5V
VGS (th) (Max) @ Id	1.1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	1.82nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	110pF @ 16V
Verpackung	Tape & Reel (TR)








NVA4153NT1G ist neu im Original, Suche NVA4153NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVA4153NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVA4153NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVAR-02VS JST CONN SOCKET 2POS 7.92MM WHITE</p>	 <p>NVA4001NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 20V SC75</p>	 <p>NVATS4A104PZT4G AMI Semiconductor / ON Semiconductor MOSFET P-CHANNEL 30V 82A ATPAK</p>	 <p>NVATS4A103PZT4G AMI Semiconductor / ON Semiconductor MOSFET P-CHANNEL 30V 60A ATPAK</p>
 <p>NVATS4A102PZT4G AMI Semiconductor / ON Semiconductor MOSFET P-CHANNEL 30V 44A ATPAK</p>	 <p>NVATS4A101PZT4G AMI Semiconductor / ON Semiconductor MOSFET P-CHANNEL 30V 27A ATPAK</p>	 <p>NVATS5A106PLZT4G AMI Semiconductor / ON Semiconductor MOSFET P-CHANNEL 40V 33A ATPAK</p>	 <p>NVATS5A107PLZT4G AMI Semiconductor / ON Semiconductor MOSFET P-CHANNEL 40V 55A ATPAK</p>

heiße Teile

Mehr

 151REB90	 7MBI75SA120B	 AAAF5060PBESEEVGC	 APTCC3063	 BSS670S2LH6327
 C3216X7R1H224M115AA	 C3225X5R1H475M250AB	 CC0805KRX7R8BB223	 CC1206KX7RZBB332	 CL02C120GO2GNNC
 CM9926-PR-L	 CMPD2836E	 D188S1200T	 DIM2400ESM17-E	 DS1107SM33
 DS1743E-5	 IDT71321LA25PF	 INA115AU/1K	 IP-264-IU	 IXTM21N50
 LP2992AILDX-5.0/NOPB	 LT1376IS8-5	 MAX16832AASA+T	 MAX3349EAEBE+T	 MAX8538EEI
 MBRF10H150CTG	 MCD95-18io1	 NP160N04	 P1200SA-L	 PCA9629PW/S911
 PE42650AMLI	 QS3384QG	 RB751S-40T1G	 RMCF0805FT432R	 S-1142B90I-E6T1U
 S-817B30AUA-CWT-T2	 SBR4045CTFP-G	 SC33262DR2	 SDA250AA40	 SMAJ30CA-13
 SMCJ70A-E3/9AT	 STV0680B-003	 SY100S839VZI	 SY10H841ZH	 TK71530ASCL
 TLV1117CKVURG3	 TLV2324IPWR	 TPSMB22AHE3/5BT	 VI-231-EV	 VI-J3M-EZ

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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